

# S3091

DEVICE SPECIFICATION

## SONET/SDH/ATM OC-192 16:1 Transmitter

### FEATURES

- Silicon Germanium BiCMOS technology
- Complies with Telcordia, ITU-T, and G.709 specifications
- On-chip high-frequency PLL for clock generation
- OC-192 with FEC and Digital Wrapper (DW) (9.953 to 10.709 Gbps)
- Reference frequency of 155.52 or 622.08 MHz (or equivalent FEC or DW rate)
- 16-bit parallel, 622.08 Mbps LVDS data path
- Lock detect/Phase error indicator
- Low jitter CML differential or single-ended serial interface
- Dual +3.3 V and -5.2 V power supply
- Supports line timing
- Internal FIFO to decouple transmit clocks
- 311.04 MHz or 622.08 MHz parallel input clock
- Programmable skew on 311.04 MHz parallel clock mode
- 148-pin CBGA package
- Typical power dissipation 2.3 W

### APPLICATIONS

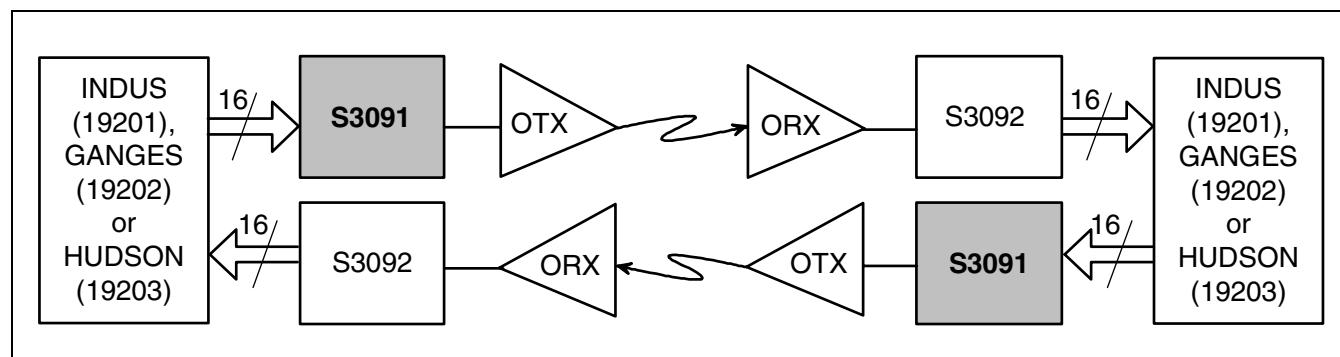
- SONET/SDH-based transmission systems
- SONET/SDH modules
- SONET/SDH test equipment
- ATM over SONET/SDH
- Section repeaters
- Add Drop Multiplexers (ADM)
- Broad-band cross-connects
- Fiber optic terminators
- Fiber optic test equipment

### GENERAL DESCRIPTION

The S3091 SONET/SDH MUX chip is a fully integrated serializer with SONET OC-192 with FEC and Digital Wrapper (9.953 to 10.709 Gbps) rate capability. The chip performs all necessary parallel-to-serial functions in conformance with SONET/SDH/Digital Wrapper transmission standards. The device is suitable for SONET-based ATM applications. Figure 1 shows a typical network application.

On-chip clock synthesis PLL components are contained in the S3091 MUX chip, allowing the use of a slower external transmit clock reference. The chip can be used with a 155.52 or 622.08 MHz reference clock (or equivalent FEC or DW rate), in support of existing system clocking schemes.

Figure 1. System Block Diagram



## Contents

FEATURES .....	1
APPLICATIONS .....	1
GENERAL DESCRIPTION .....	1
CONTENTS .....	2
LIST OF FIGURES .....	3
LIST OF TABLES .....	3
SONET OVERVIEW .....	4
Data Rates and Signal Hierarchy .....	4
Frame and Byte Boundary Detection .....	4
S3091 OVERVIEW .....	6
S3091 ARCHITECTURE/FUNCTIONAL DESIGN .....	7
MUX OPERATION .....	7
Clock Divider and Phase Detector .....	7
Timing Generator .....	7
Parallel-to-Serial Converter .....	8
FIFO .....	8
FIFO Initialization .....	8
Power Sequencing .....	8
ORDERING INFORMATION .....	25

## List of Figures

Figure 1. System Block Diagram .....	1
Figure 2. SONET Structure .....	4
Figure 3. STS-192 Frame Format .....	5
Figure 4. Functional Block Diagram .....	6
Figure 5. S3091 Pinout .....	12
Figure 6. S3091 148-Pin CBGA Package .....	13
Figure 7. AC Input Timing (PICLK/N = 622.08 MHz) .....	18
Figure 8. AC Input Timing (PICLK/N = 311.04 MHz) .....	19
Figure 9. Phase Adjust Timing .....	20
Figure 10. Differential Voltage Measurement .....	20
Figure 11. CML Output to -5.2 V ECL Input DC Coupled Termination, Reference Only .....	21
Figure 12. S3091 LVDS Driver to LVDS Input, Reference Only .....	21
Figure 13. LVDS Driver to S3091 LVDS Input Direct Coupled Termination, Reference Only .....	21
Figure 14. LVDS Driver to S3091 LVDS Input AC Coupled Termination, Reference Only .....	22
Figure 15. External Loop Filter .....	22
Figure 16. S3091 622.08 MHz REFCLK Phase Noise Limit .....	23
Figure 17. S3091 155.52 MHz REFCLK Phase Noise Limit .....	24

## List of Tables

Table 1. SONET Signal Hierarchy .....	4
Table 2. FEC Modes .....	7
Table 3. Reference Frequency .....	8
Table 4. Clock Select .....	8
Table 5. Skew Select .....	8
Table 6. Input Pin Assignment and Descriptions .....	9
Table 7. Output Pin Assignment and Descriptions .....	10
Table 8. Common Pin Assignment and Descriptions .....	11
Table 9. Thermal Management .....	13
Table 10. Performance Specifications .....	14
Table 11. Absolute Maximum Ratings .....	15
Table 12. Recommended Operating Conditions .....	15
Table 13. LVTTL Input DC Characteristics .....	16
Table 14. LVTTL Output DC Characteristics .....	16
Table 15. Differential CML Output DC Characteristics .....	16
Table 16. Internally Biased Differential ECL Input DC Characteristics .....	16
Table 17. Internally Biased LVDS Input Characteristics .....	17
Table 18. LVDS Output DC Characteristics (See Figure 12) .....	17
Table 19. AC Transmitter Timing Characteristics (PICLK/N = 622.08 MHz) .....	18
Table 20. AC Transmitter Timing Characteristics (PICLK/N = 311.04 MHz) .....	19
Table 21. External Loop Filter Components .....	19

## SONET OVERVIEW

Synchronous Optical Network (SONET) is a standard for connecting one fiber system to another at the optical level. SONET, together with the Synchronous Digital Hierarchy (SDH) administered by the ITU-T, forms a single international standard for fiber interconnect between telephone networks of different countries. SONET is capable of accommodating a variety of transmission rates and applications.

The SONET standard is a layered protocol with four separate layers defined. These are:

- Photonic
- Section
- Line
- Path

Figure 2 shows the layers and their functions. Each of the layers has overhead bandwidth dedicated to administration and maintenance. The photonic layer simply handles the conversion from electrical to optical and back with no overhead. It is responsible for transmitting the electrical signals in optical form over the physical media. The section layer handles the transport of the framed electrical signals across the optical cable from one end to the next. Key functions of this layer are framing, scrambling, and error monitoring. The line layer is responsible for the reliable transmission of the path layer information stream carrying voice, data, and video signals. Its main functions are synchronization, multiplexing, and reliable transport. The path layer is responsible for the actual transport of services at the appropriate signaling rates.

### Data Rates and Signal Hierarchy

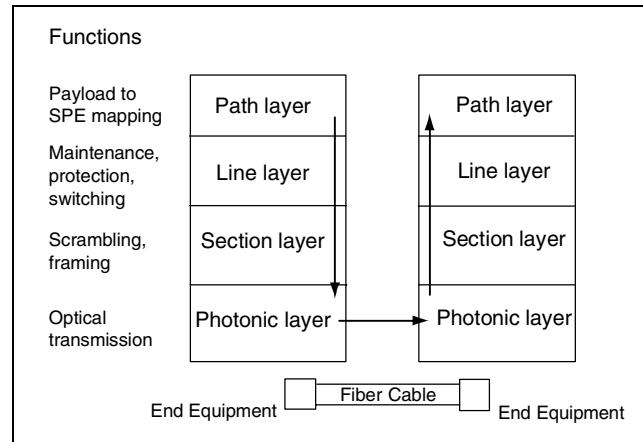
Table 1 contains the data rates and signal designations of the SONET hierarchy. The lowest level is the basic SONET signal, referred to as the synchronous transport signal level-1 (STS-1). An STS-N signal is made up of N byte-interleaved STS-1 signals. The optical counterpart of each STS-N signal is an optical carrier level-N signal (OC-N). The chip supports OC-192 with FEC and Digital Wrapper (9.95328 to 10.709 Gbps) rates.

## Frame and Byte Boundary Detection

The SONET/SDH fundamental frame format for STS-192 consists of 576 transport overhead bytes followed by Synchronous Payload Envelope (SPE) bytes. This pattern of 576 overhead and 16,704 SPE bytes is repeated nine times in each frame. Frame and byte boundaries are detected using the A1 and A2 bytes found in the transport overhead. (See Figure 3.)

For more details on SONET operations, refer to the Bellcore SONET standard document.

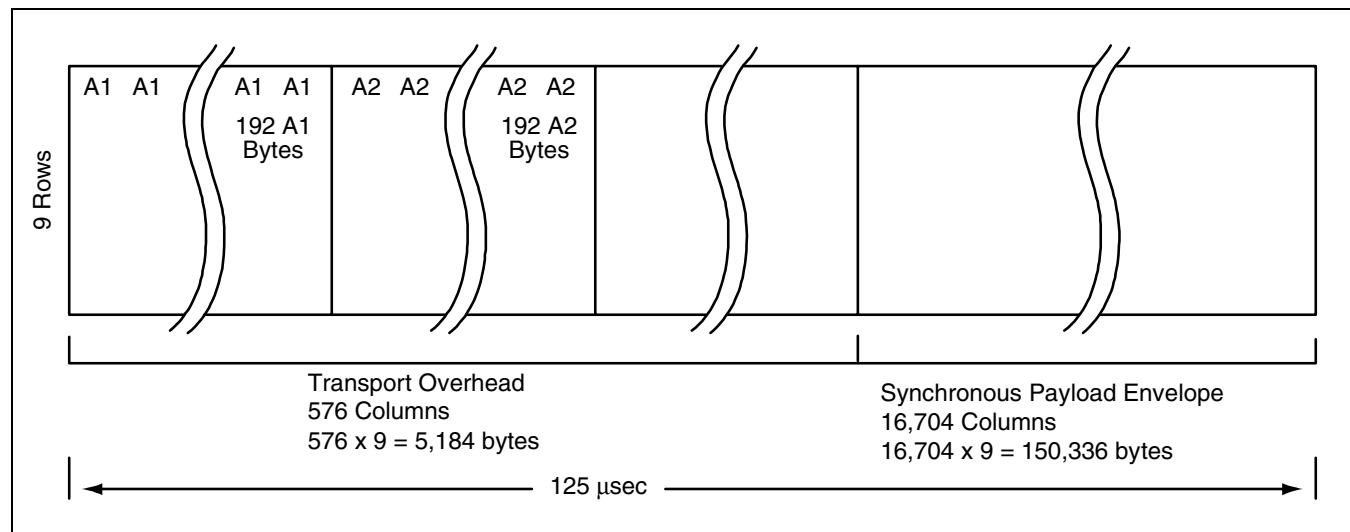
*Figure 2. SONET Structure*



*Table 1. SONET Signal Hierarchy*

Elec.	ITU-T	Optical	Data Rate (Mbps)
STS-1		OC-1	51.84
STS-3	STM-1	OC-3	155.52
STS-12	STM-4	OC-12	622.08
STS-24	STM-8	OC-24	1244.16
STS-48	STM-16	OC-48	2488.32
STS-192	STM-64	OC-192	9953.28

Figure 3. STS-192 Frame Format



## S3091 OVERVIEW

The S3091 transmitter implements SONET/SDH serialization and transmission functions. This chip can be used to implement the front end of SONET equipment, which consists primarily of the serial transmit interface and the serial receive interface. The chip includes parallel-to-serial conversion and system timing. The system timing circuitry consists of a high-speed phase detector, clock dividers, and clock distribution throughout the front end.

The sequence of transmitter operations is as follows:

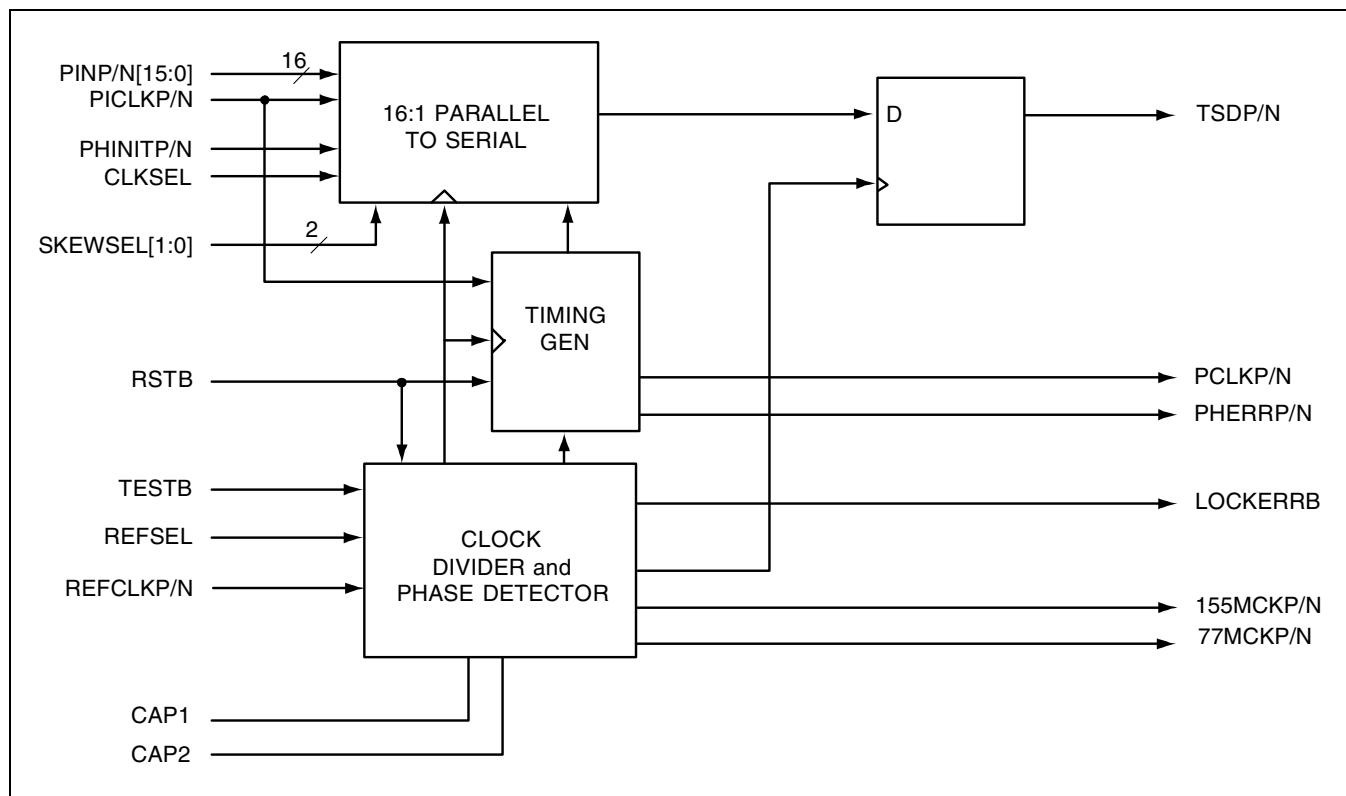
1. 16-bit parallel input
2. Parallel-to-serial conversion
3. Serial output

Internal clocking and control functions are transparent to the user. Details of data timing can be seen in Figures 7 and 8.

### Suggested Interface Devices

AMCC	S3092	OC-192 CDR+DeMUX
AMCC	19201	OC-192 to OC-48 MUX/DeMUX
AMCC	19202	OC-192 SONET/SDH Mapper
AMCC	19203	OC-192 Digital Wrapper

Figure 4. Functional Block Diagram



## **S3091 ARCHITECTURE/FUNCTIONAL DESIGN**

### **MUX OPERATION**

The S3091 performs serialization in the processing of a transmit SONET STS-192 bit serial data stream. It converts the 16-bit parallel 622.08 Mbps data stream to bit serial format at 9.953 Gbps.

A high-frequency bit clock is generated from a 155.52 or 622.08 MHz (or equivalent FEC or DW rates) frequency reference by using a frequency synthesizer that consists of an on-chip phase-lock loop circuit with a divider, VCO and loop filter.

### **Clock Divider and Phase Detector**

The clock divider and phase detector, shown in the block diagram in Figure 4, contains monolithic PLL components that generate signals required to drive the loop filter. See Table 2 for REFCLK required.

In order for the VCO clock frequency to meet the accuracy required for operation in a SONET system, the REFCLK input must be generated from a differential ECL crystal oscillator in which the frequency accuracy equals the value stated in Table 10.

Oscillator phase noise allowable can be defined best by looking at plots of oscillators that allow the part to meet SONET jitter generation specifications of 100 mUlpp. As can be seen from Figures 16 and 17, two different vendors' oscillators can yield similar results. For 622 MHz REFCLK, the 82 mUlpp graph is at the noise floor of the part.

For best jitter generation, use a 622.08 MHz oscillator with a phase noise that meets or exceeds the phase noise plots shown in Figure 16, or a 155.52 MHz oscillator with a phase noise that meets or exceeds the phase noise plots in Figure 17.

### **Timing Generator**

The timing generator function, shown in Figure 4, provides two separate functions. It provides a 16-bit parallel rate clock and a mechanism for aligning the phase between the incoming clock and the clock that loads the parallel-to-serial shift register.

The PCLK output is a 16-bit parallel rate clock. For STS-192, the PCLK frequency is 622.08 MHz. PCLK is intended for use as a 16-bit parallel speed clock for upstream multiplexing and overhead processing circuits. Using PCLK for upstream circuits will ensure a stable frequency and phase relationship between the data coming into and leaving the S3091 device.

In the parallel-to-serial conversion process, the incoming data is passed from the PICLK clock timing domain to the internally generated byte clock timing domain using an internal FIFO.

The timing generator also produces a feedback reference clock to the clock synthesizer. A counter divides the synthesized clock down to the same frequency as the reference clock (REFCLK). The PLL in the clock synthesizer maintains the stability of the synthesized clock by comparing the phase of the feedback clock to that of the reference clock (REFCLK). The modulus of the counter is a function of the reference clock frequency and the operating frequency.

*Table 2. FEC Modes*

Error Correcting Capability	Code Rate showing Bandwidth Expansion due to code words and FSB	Increased TSD Frequency	Increased Input Clock (REFCLK) Frequency
0 bytes per 255-byte block	0% Increase	9.953 Gbps	622.08 MHz
3 bytes per 255-byte block	2.82% Increase	10.234 Gbps	639.62 MHz
4 bytes per 255-byte block	3.66% Increase	10.317 Gbps	644.84 MHz
5 bytes per 255-byte block	4.51% Increase	10.402 Gbps	650.13 MHz
6 bytes per 255-byte block	5.37% Increase	10.488 Gbps	655.48 MHz
7 bytes per 255-byte block	6.25% Increase	10.575 Gbps	660.96 MHz
8 bytes per 255-byte block	7.14% Increase	10.664 Gbps	666.51 MHz
Digital Wrapper (OTU2)	7.59% Increase	10.709 Gbps	669.33 MHz

### Parallel-to-Serial Converter

The parallel-to-serial converter shown in Figure 4 is comprised of two byte-wide registers. The PICLK (622.08 MHz or 311.04 MHz dual edge clock) clocks in the data from the PINP/N[15:0] bus to the first register of the parallel-to-serial register. The second register is a parallel loadable shift register, which takes its parallel input from the first register.

An internally generated byte clock activates the parallel data transfer between registers. The serial data is shifted out of the second register.

If the 311.04 MHz dual edge PICLK mode is selected, PICLK skew relative to PINP/N[15:0] may be introduced to optimize data and clock setup and hold times. SKEWSEL[1:0] may be used to control the skew which is nominally 815 ps. See Table 5 for skew selections.

### FIFO

A FIFO is added to decouple the internal and external parallel clocks. The internally generated divide-by-16 clock is used to clock out data from the FIFO. PHINIT and LOCKERRB are used to center or reset the FIFO. The PHINIT and LOCKERRB signals will center the FIFO after the third PICLK pulse. (See Figure 9.) This ensures that PICLK is stable. This scheme allows the user to have an infinite PCLK to PICLK delay through the ASIC. Once the FIFO is centered, the PCLK to PICLK delay can have a maximum drift as specified in Table 20.

### FIFO Initialization

The FIFO can be initialized in one of the following three ways:

1. During power up, once the PLL has locked to the reference clock provided on the REFCLK pins, the LOCKERRB will go active and initialize the FIFO.
2. When RSTB goes active, the entire chip is reset. This causes the PLL to go out of lock, and thus the LOCKERRB goes inactive. When the PLL reacquires the lock, the LOCKERRB goes active and initializes the FIFO. Note that PCLK does not toggle when RSTB is active.
3. The user can also initialize the FIFO by raising PHINIT.

During normal running operation, the incoming data is passed from the PICLK timing domain to the internally generated divide-by-16 clock timing domain. Although the frequency of PICLK and the internally generated clock is the same, their phase relationship is arbitrary.

*Table 3. Reference Frequency*

REFSEL	REFCLK
0	155.52 MHz (or equivalent FEC or DW rate)
1	622.08 MHz (or equivalent FEC or DW rate)

To prevent errors caused by short setup or hold times between the two timing domains, the timing generator circuitry monitors the phase relationship between PICLK and the internally generated clock. When a potential setup or hold time violation is detected, Phase Error (PHERR) goes High. If the condition persists, PHERR will remain High. When PHERR conditions occur, PHINIT should be activated to recenter the FIFO (at least 10 ns). This can be done by connecting PHERR to PHINIT. When realignment occurs, four to ten bytes of data will be lost. The user can also take in the PHERR signal, process it, and send an output to PHINIT in such a way that idle bytes are lost during the realignment process. PHERR will go inactive when the realignment is complete. (See Figure 9, *Phase Adjust Timing*.)

### Power Sequencing

In order to avoid latchup, it is required that the -5.2 V power be applied to the S3091 for a minimum of 50 ms before 3.3 V power is applied.

*Table 4. Clock Select*

CLKSEL	PICLK Frequency
0	622.08 MHz (or equivalent FEC or DW rate)
1	311.04 MHz (or equivalent FEC or DW rate)

*Table 5. Skew Select*

SKEWSEL[1]	SKEWSEL[0]	311 PICLK Target Skew
0	0	915 ps
0	1	1015 ps
1	0	715 ps
1	1	815 ps

Table 6. Input Pin Assignment and Descriptions

Pin Name	Level	I/O	Pin #	Description
PINP0	LVDS	I	N2	<b>Parallel Data Input.</b> A 16-bit parallel, 622.08 Mbps, aligned to the PICLK parallel input clock. PINP/N[15] is the most significant bit (corresponding to bit 1 of each word, the first bit transmitted). PINP/N[0] is the least significant bit (corresponding to bit 16 of each word, the last bit transmitted). PINP/N[15:0] is sampled on the rising edge of PICLK (when CLKSEL = 0) or on the rising and falling edge of PICLK (when CLKSEL = 1). Internally biased and terminated.
PINN0			N3	
PINP1			P3	
PINN1			P4	
PINP2			N4	
PINN2			N5	
PINP3			P5	
PINN3			P6	
PINP4			N6	
PINN4			N7	
PINP5			P7	
PINN5			P8	
PINP6			N8	
PINN6			N9	
PINP7	LVDS	I	P9	
PINN7			P10	
PINP8			M11	
PINN8			M12	
PINP9			N12	
PINN9			N13	
PINP10			N14	
PINN10			M14	
PINP11	LVDS	I	L13	
PINN11			K13	
PINP12			K14	
PINN12			J14	
PINP13			H14	
PINN13	LVTTL	I	G14	
PINP14			G13	
PINN14			F13	
PINP15			F14	
PINN15			E14	
PICLK_P	LVDS	I	D14	<b>Parallel Input Clock.</b> A 622.08 MHz or dual edge 311.04 MHz nominally 50% duty cycle input clock, to which PINP/N[15:0] is aligned.
PICLK_N			C14	PICLK is used to transfer the data on the PIN inputs into a holding register in the parallel-to-serial converter. Internally biased and terminated.
TESTB	LVTTL	I	C6	<b>Test Clock Enable.</b> Active Low. Set Low to provide access to the PLL during production tests. (Pull High for normal operation.)
REFCLK_P	Diff. ECL	I	B1	<b>Reference Clock.</b> Input used as the reference for the internal bit clock frequency synthesizer. Internally terminated and biased.
REFCLK_N			C1	
RSTB	LVTTL	I	A7	<b>Master Reset.</b> Active Low. Reset input for the device. For correct reset, this input must be asserted Low for 100 ns. During reset, PCLK does not toggle.
CAP1	Analog	I	B4	<b>Loop Filter Capacitors.</b> Connections for external loop filter capacitor and resistors. (See Figure 15.)
CAP2			C4	

Table 6. Input Pin Assignment and Descriptions (Continued)

Pin Name	Level	I/O	Pin #	Description
REFSEL	LV TTL	I	M2	<b>Reference Select.</b> Used to select the reference clock frequency. See Table 3.
PHINITP PHINITN	LVDS	I	C13 B13	<b>Phase Initialization.</b> Asynchronous input that initializes the phase adjust circuit. (See Figure 9.)
CLKSEL	LV TTL	I	A6	<b>Clock Select.</b> Used to select between the 622.08 MHz or 311.04 MHz dual edge clock on the PICLK/N. See Table 4.
SKEWSEL1 SKEWSEL0	LV TTL	I	J13 D13	Allows magnitude error in delaying the 311 PICLK to compensate for the variations in the data valid window due to Inter-Symbol Interference (ISI) and static skew. See Table 5.

Table 7. Output Pin Assignment and Descriptions

Pin Name	Level	I/O	Pin #	Description
TSDP TSDN	Diff. CML	O	G1 J1	<b>Transmit Serial Data.</b> Serial data stream signals, normally connected to an optical transmitter module. Use Coplanar Waveguide Structure for best results. See Layout Recommendation application note. See Characterization Report for S <sub>22</sub> plot.
PCLKP PCLKN	LVDS	O	B11 A11	<b>Parallel Clock.</b> A 622.08 MHz clock. It is normally used to coordinate transfers between upstream logic and the S3091 device.
155MCKP 155MCKN	LVDS	O	B10 B9	<b>155.52 MHz Clock Output.</b> 155.52 MHz clock output from the clock synthesizer. The output should be connected to the reference clock input of the external clock recovery function (such as the S3092). Pull-down resistors may be removed to minimize power.
77MCKP 77MCKN	LVDS	O	A10 A9	<b>77.76 MHz Clock Output.</b> 77.76 MHz clock output from the clock synthesizer. For test purposes only. Pull-down resistors may be removed to minimize power.
LOCK-ERRB	LV TTL	O	C12	<b>Lock Error/Phase Error.</b> Active Low. Goes inactive after an internal delay and the PLL has locked to the clock provided on the REF-CLK pins. LOCKERRB goes active for at least 100 ns when PHERR goes active. LOCKERRB stays active as long as PHERR is active. LOCKERRB is an asynchronous output.
PHERRP PHERRN	LVDS	O	B12 A12	<b>Phase Error.</b> Pulses High during each PCLK cycle for which there is a potential set-up/hold timing violation between the internal byte clock and PICLK timing domains.

Table 8. Common Pin Assignment and Descriptions

Pin Name	Level	Pin #	Description
AVEE	-5.2 V	B8, C8, D1, E2, L2, M5, M8, N11	Analog V <sub>EE</sub>
VEE_FILTER	-5.2 V	A3	Analog V <sub>EE</sub> for Filter
VEE_VCO	-5.2 V	A5	Analog V <sub>EE</sub> for VCO
DGND	GND = 0 V	A8, A13, A14, B7, B14, C10, E13, L14, M4, M7, M10, N1, N10, P1, P2, P11, P12, P13, P14	Digital Ground
AGND	GND = 0 V	A1, A2, A4, B2, B3, B5, B6, C2, C3, C5, D2, E1, F1, F2, H1, H2, M1, K1, K2, L1	Analog GND
THERMALGND	GND = 0 V	E6, E7, E8, E9, E10, F5, F6, F7, F8, F9, F10, G5, G6, G7, G8, G9, G10, H5, H6, H7, H8, H9, H10, J5, J6, J7, J8, J9, J10, K5, K6, K7, K8, K9, K10	Thermal Ground
VCCLVDS	+3.3 V	C9, H13, M3, M6, M9, M13	LVDS V <sub>CC</sub>
VCCLVTTL	+3.3 V	C7	LVTTL V <sub>CC</sub>

Note: All digital, analog, and thermal grounds are connected together on the package.

Figure 5. S3091 Pinout

	1	2	3	4	5	6	7	8	9	10	11	12	13	14
<b>A</b>	AGND	AGND	VEE FILTER	AGND	VEE VCO	CLKSEL	RSTB	DGND	77MCKN	77MCKP	PCLKN	PHERRN	DGND	DGND
<b>B</b>	REFCLKP	AGND	AGND	CAP1	AGND	AGND	DGND	AVEE	155MCKN	155MCKP	PCLKP	PHERRP	PHINITN	DGND
<b>C</b>	REFCLKN	AGND	AGND	CAP2	AGND	TESTB	VCCLVTTL	AVEE	VCCLVDS	DGND		LOCKERRB	PHINITP	PICLKN
<b>D</b>	VEE REFCLK	AGND										SKEWSEL0	PICLKP	
<b>E</b>	AGND	AVEE						THERMAL GND	THERMAL GND	THERMAL GND	THERMAL GND	DGND	PIN15N	
<b>F</b>	AGND	AGND						THERMAL GND	THERMAL GND	THERMAL GND	THERMAL GND		PIN14N	PIN15P
<b>G</b>	TSDP							THERMAL GND	THERMAL GND	THERMAL GND	THERMAL GND		PIN14P	PIN13N
<b>H</b>	AGND	AGND						THERMAL GND	THERMAL GND	THERMAL GND	THERMAL GND		VCCLVDS	PIN13P
<b>J</b>	TSDN							THERMAL GND	THERMAL GND	THERMAL GND	THERMAL GND		SKEWSEL1	PIN12N
<b>K</b>	AGND	AGND						THERMAL GND	THERMAL GND	THERMAL GND	THERMAL GND		PIN11N	PIN12P
<b>L</b>	AGND	AVEE											PIN11P	DGND
<b>M</b>	AGND	REFSEL	VCCLVDS	DGND	AVEE	VCCLVDS	DGND	AVEE	VCCLVDS	DGND	PIN8P	PIN8N	VCCLVDS	PIN10N
<b>N</b>	DGND	PINOP	PIN0N	PIN2P	PIN2N	PIN4P	PIN4N	PIN6P	PIN6N	DGND	AVEE	PIN9P	PIN9N	PIN10P
<b>P</b>	DGND	DGND	PIN1P	PIN1N	PIN3P	PIN3N	PIN5P	PIN5N	PIN7P	PIN7N	DGND	DGND	DGND	DGND
<b>S3091</b> <b>(Package TOP View)</b> <b>(Die BOTTOM View)</b>														

Figure 6. S3091 148-Pin CBGA Package

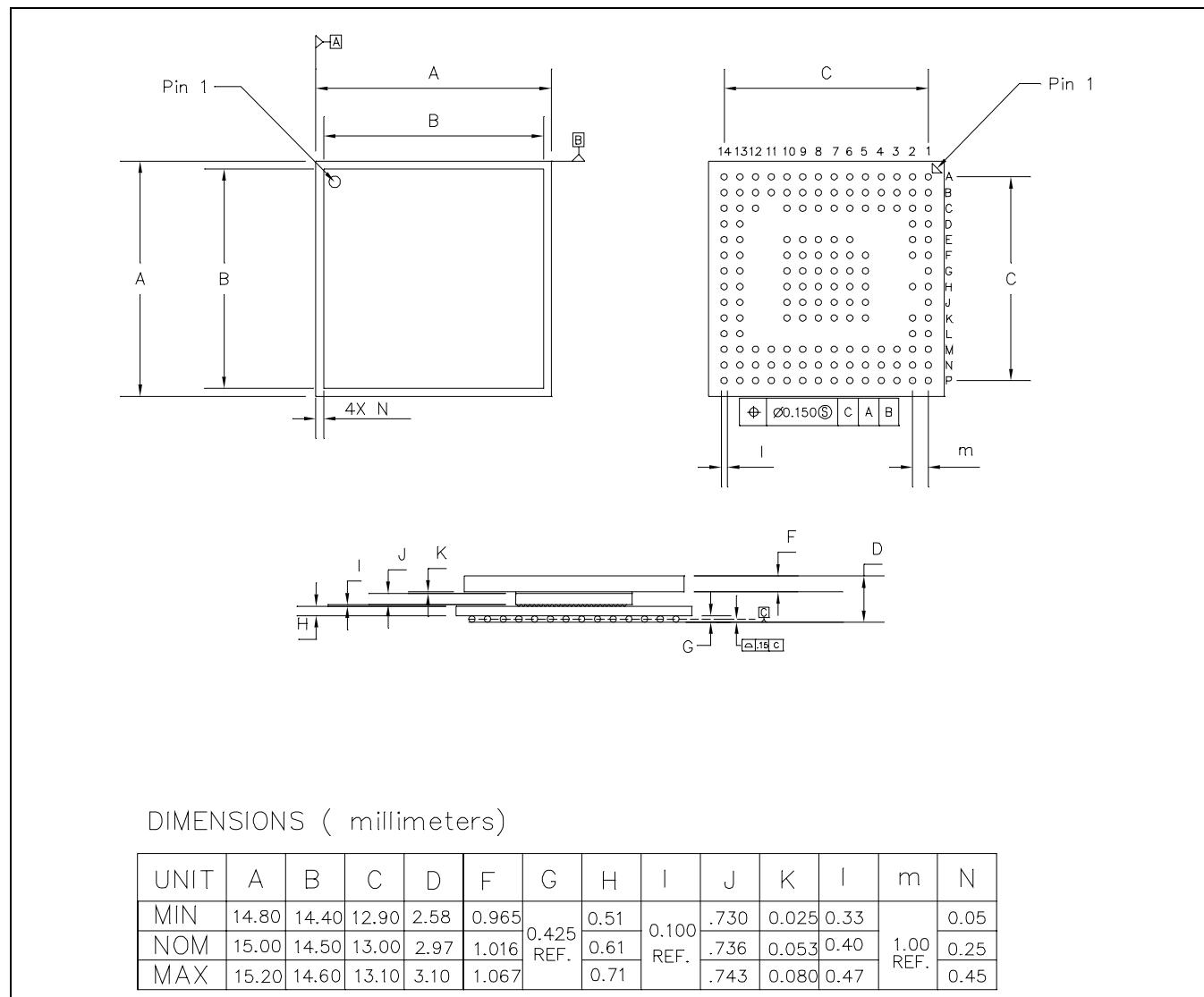


Table 9. Thermal Management

Device	Package Max Power (70°C Ambient)	$\Theta_{ja}$	$\Theta_{jc}$
S3091	2.68 W	20.5°C/W	3.0°C/W

Note: See application note for simulation results, thermal management suggestions and thermal profile for attachment.

Table 10. Performance Specifications

Parameter	Min	Typ	Max	Units	Conditions
Nominal VCOCLK Center Frequency	9.953		10.709	GHz	
Data Output Jitter STS-192 with 622.08 MHz REFCLK.			82	mUIpp	Limited B.W., 50 kHz to 80 MHz, BER = 1E-12.
Data Output Jitter STS-192 with 155.52 MHz REFCLK.		100		mUIpp	Limited B.W., 50 kHz to 80 MHz, 49/51 duty cycle REFCLK.
TSDP/N Output Return Loss ( $S_{22}$ )			-12	dB	DC – 10 GHz
Reference Clock Frequency Tolerance	-100		+100	ppm	$\pm 20$ ppm is required to meet SONET output frequency specification.
Reference Clock Input Duty Cycle (622.08 MHz) (or equivalent FEC or DW rate)	45		55	%	
Reference Clock Input Duty Cycle (155.52 MHz) (or equivalent FEC or DW rate)	49		51	%	Required for best jitter performance.
Reference Clock Rise and Fall Times for 155.52 MHz Clk. (or equivalent FEC or DW rate)	0.2		0.8	ns	20% to 80% of amplitude.
Reference Clock Rise and Fall Times for 622.08 MHz Clk. (or equivalent FEC or DW rate)	0.1		0.5	ns	20% to 80% of amplitude.
Acquisition Lock Time (phase lock)		16	25	$\mu$ s	After the release of RSTB, with device already powered up and with a valid REFCLK. Guaranteed, but not tested.

*Table 11. Absolute Maximum Ratings*

Parameter	Min	Typ	Max	Units
Storage Temperature	-55		150	°C
VCC 3.3 V Supply	-0.5		3.6	V
VEE -5.2 V Supply	0.5		-7.0	V
LVTTL Input Voltage	-0.5		V <sub>CC</sub> +0.5	V
LVDS Input Voltage	0		V <sub>CC</sub>	V
LVDS Output Voltage	0		V <sub>CC</sub>	V
ECL Input Voltage	V <sub>EE</sub> -0.25		AGND	V
CML Output Voltage	V <sub>EE</sub> -0.25		AGND	V
LVTTL Output Voltage	AGND -0.5		V <sub>CC</sub> +0.5	V
CML Output Current per pin			13	mA
LVDS Input Current per pin			10	mA
LVTTL Input Current per pin	-450		1000	µA
LVTTL Output Current per pin			2	mA
LVDS Output Current per pin			15	mA
ECL Input Current per pin			15	mA

#### **Electrostatic Discharge (ESD) Ratings**

The S3091 is rated to the following voltages based on the human body model:

1. All pins are rated at 100 Volts.

Standards for ESD protection should be adhered to when handling the devices to ensure that they are not damaged. The standards to be used are defined in ANSI standard ANSI/ESD S20.20-1999, "Protection of Electrical and Electronic Parts, Assemblies and Equipment." Contact your local FAE or sales representative for ESD application notes.

*Table 12. Recommended Operating Conditions*

Parameter	Min	Typ	Max	Units
Ambient Temperature Under Bias (Commercial)	0		+70	°C
Junction Temperature Under Bias	40		125	°C
Voltage on V <sub>CC</sub> with Respect to GND	3.135	3.3	3.465	V
Voltage on V <sub>EE</sub> with Respect to GND	-4.94	-5.2	-5.46	V
I <sub>CC</sub> Supply Current		290	360	mA
I <sub>EE</sub> Supply Current		260	320	mA

*Table 13. LVTTL Input DC Characteristics*

Parameters	Description	Min	Typ	Max	Units	Condition
$V_{IH}$	Input High Voltage	2.0		3.465	V	TTL $V_{CC} = \text{Max}$
$V_{IL}$	Input Low Voltage	0.0		0.8	V	TTL $V_{CC} = \text{Min}$
$I_{IH}$	Input High Current			20	$\mu\text{A}$	$V_{IN} = 2.4 \text{ V}$
$I_{IL}$	Input Low Current	-500			$\mu\text{A}$	$V_{IN} = 0.5 \text{ V}$

*Table 14. LVTTL Output DC Characteristics*

Parameters	Description	Min	Typ	Max	Units	Condition
$V_{OH}$	Output High Voltage	2.4			V	$V_{CC} = \text{Min}$ $I_{OH} = -30 \mu\text{A}$
$V_{OL}$	Output Low Voltage			0.5	V	$V_{CC} = \text{Min}$ $I_{OL} = 1 \text{ mA}$

*Table 15. Differential CML Output DC Characteristics*

Parameters	Description	Min	Typ	Max	Units	Condition
$V_{OL}$	Output Low Voltage	AGND - 1.25		AGND - 0.80	V	100 $\Omega$ line-to-line.
$V_{OH}$	Output High Voltage	AGND - 0.55		AGND - 0.25	V	100 $\Omega$ line-to-line.
$\Delta V_{OUTDIFF}$ Data	Serial Output Differential Voltage Swing	1000		1500	mV	100 $\Omega$ line-to-line. See Figure 10.
$\Delta V_{OUTSINGLE}$ Data	Serial Output Single-ended Voltage Swing	500		750	mV	100 $\Omega$ line-to-line. See Figure 10.
$R_{SINGLE}$	Single-ended Resistance	40		60	$\Omega$	Over process, voltage and temperature range.

*Table 16. Internally Biased Differential ECL Input DC Characteristics*

Parameters	Description	Min	Typ	Max	Units	Comments
$\Delta V_{INDIFF}$	Differential Input Voltage Swing	300		1600	mV	See Figure 10.
$\Delta V_{INSINGLE}$	Single-ended Input Voltage Swing	150		800	mV	See Figure 10.
$R_{DIFF}$	Differential Input Resistance	80	100	120	$\Omega$	
$V_{IH}$	Input High Voltage			AGND - 0.2	V	
$V_{IL}$	Input Low Voltage	AGND - 2.0			V	

Table 17. Internally Biased LVDS Input Characteristics

Symbol	Description	Min	Typ	Max	Unit	Conditions
$V_{IH}$	Input High Voltage	1.16		2.9	V	Over process, voltage and temperature range
$V_{IL}$	Input Low Voltage	0.6		2.8	V	Over process, voltage and temperature range
$V_{INDIFF}$	Input Voltage Differential	200		2600	mV	Over process, voltage and temperature range
$V_{INSINGLE}$	Input Single-ended Voltage	100		1300	mV	Over process, voltage and temperature range
$R_{DIFF}$	Differential Input Resistance	80	100	120	$\Omega$	Over process, voltage and temperature range

Table 18. LVDS Output DC Characteristics<sup>1,2</sup> (See Figure 12)

Symbol	Description	Min	Typ	Max	Unit	Conditions
$V_{OH}$	Output High Voltage	1.25		1.8	V	Over process, voltage and temperature range
$V_{OL}$	Output Low Voltage	0.85		1.45	V	Over process, voltage and temperature range
$V_{OUTDIFF}$	Output Differential Voltage	500	740	1100	mV	Over process, voltage and temperature range
$V_{OUTSINGLE}$	Output Single-ended Voltage	250	370	550	mV	Over process, voltage and temperature range

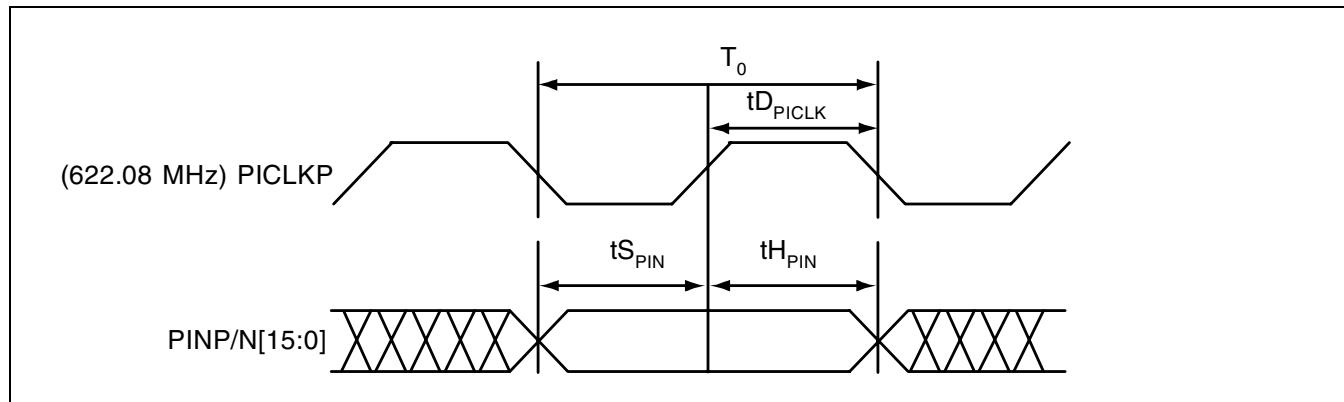
1. Output loading is 100  $\Omega$  line-to-line.  
 2. 330  $\Omega$  pull-down resistor per line to ground.

Table 19. AC Transmitter Timing Characteristics (PICLK/N = 622.08 MHz)

Symbol	Description	Min	Typ	Max	Units
	PICLK/N Duty Cycle = $tD_{PICLK}/T_0$	40		60	%
$tS_{PIN}$	PINP/N[15:0] Set-up Time w.r.t. <b>rising edge of PICLK</b> (622.08 MHz PICLK)	200			ps
$tH_{PIN}$	PINP/N[15:0] Hold Time w.r.t. <b>rising edge of PICLK</b> (622.08 MHz PICLK)	200			ps
	PCLKP/N Duty Cycle	45		55	%
	CML Output Rise and Fall Time (20% - 80%), Pattern 27 – 1			35	ps
	LVDS Output Rise and Fall Time (20% - 80%)	100		250	ps
$t_{PW}$	PHINIT Minimum Pulse Width (See Figure 9)	10			ns
$t_{PW}$	RSTB Minimum Pulse Width <sup>1</sup>	100			ns
	155MCKP/N Duty Cycle	45		55	%
	PCLK to PICLK drift after FIFO is centered			2	ns

1. Guaranteed by design.

Figure 7. AC Input Timing (PICLK/N = 622.08 MHz)



- When a set-up time is specified on LVDS signals between an input and a clock, the set-up time in picoseconds, is from the 50% point of the input to the 50% point of the clock.
- When a hold time is specified on LVDS signals between an input and a clock, the hold time in picoseconds, is from the 50% point of the clock to the 50% point of the input.

Table 20. AC Transmitter Timing Characteristics (PICLK/N = 311.04 MHz)

Symbol	Description	Min	Typ	Max	Units
	PICLK/N Duty Cycle = $tD_{PICLK}/T_0$	48		52	%
$T_R, T_F$	LVDS output rise and fall times (20% - 80%)	100		250	ps
$tS_{PIN}$	PINP/N[15:0] setup time w.r.t. <b>next edge</b> of PICLK (311.04 MHz PICLK)	1000			ps
$tH_{PIN}$	PINP/N[15:0] hold time w.r.t. <b>next edge</b> of PICLK (311.04 MHz PICLK)			600	ps
	PCLK to PICLK drift after the FIFO is centered			2	ns

Figure 8. AC Input Timing (PICLK/N = 311.04 MHz)

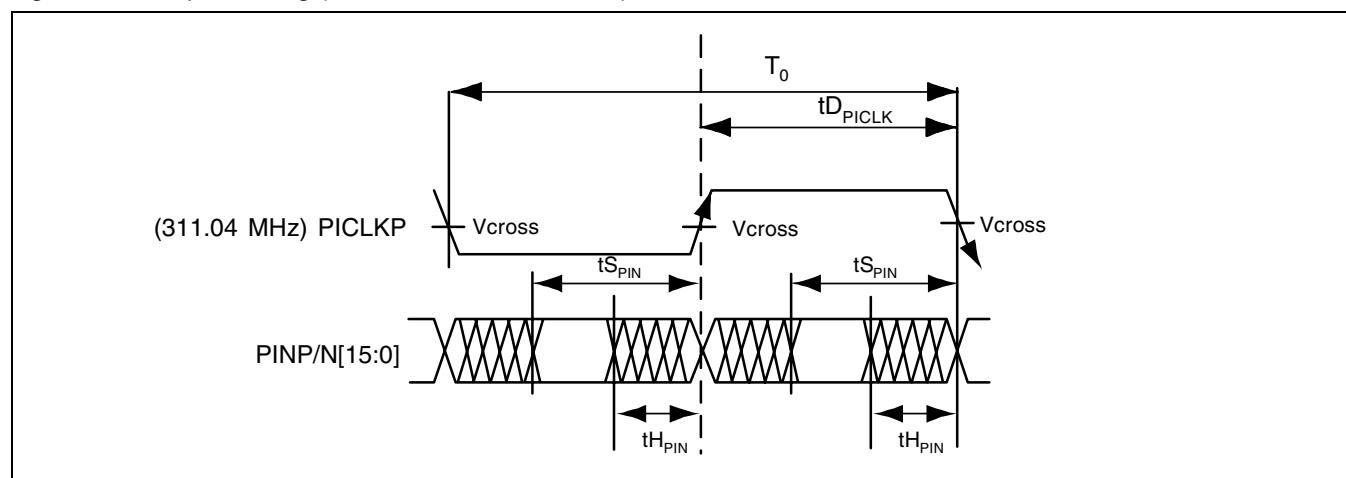
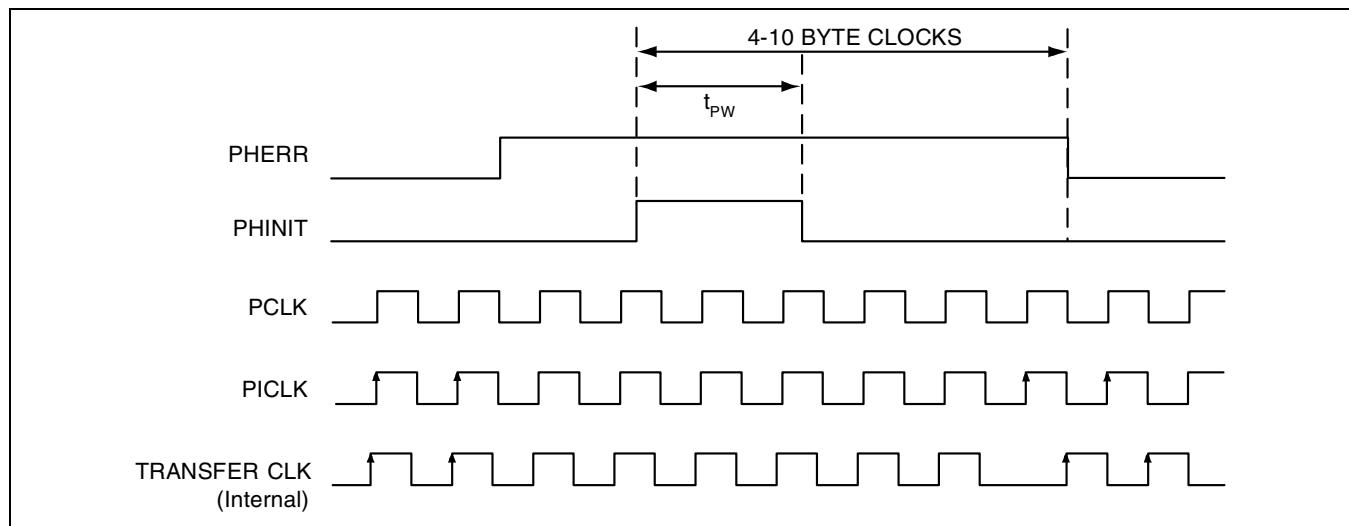


Table 21. External Loop Filter Components

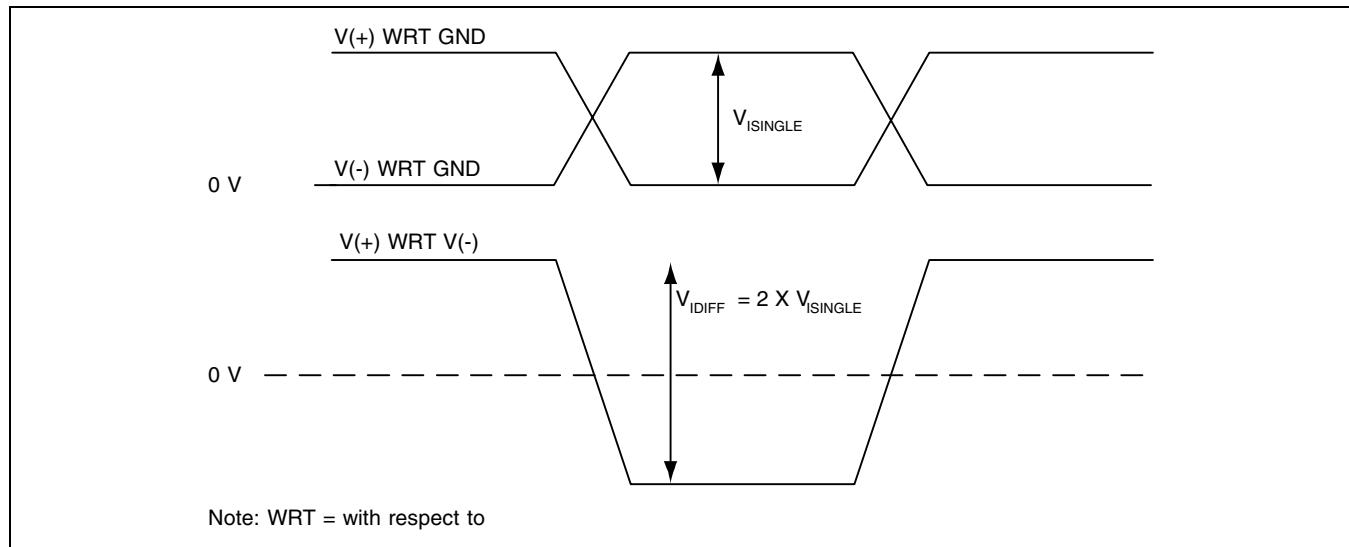
Symbol	Description	Value	Unit
$R_1, R_2$	Resistor, Surface Mount, 0402	150	$\Omega$
$C_2$	Capacitor, Surface Mount, 0603 or larger	1.0	$\mu F$

Figure 9. Phase Adjust Timing



Note: The byte clock = 622.08 MHz to 669.33 MHz.

Figure 10. Differential Voltage Measurement



Note:  $V(+) - V(-)$  is the algebraic difference of the input signals.

Figure 11. CML Output to -5.2 V ECL Input DC Coupled Termination, Reference Only

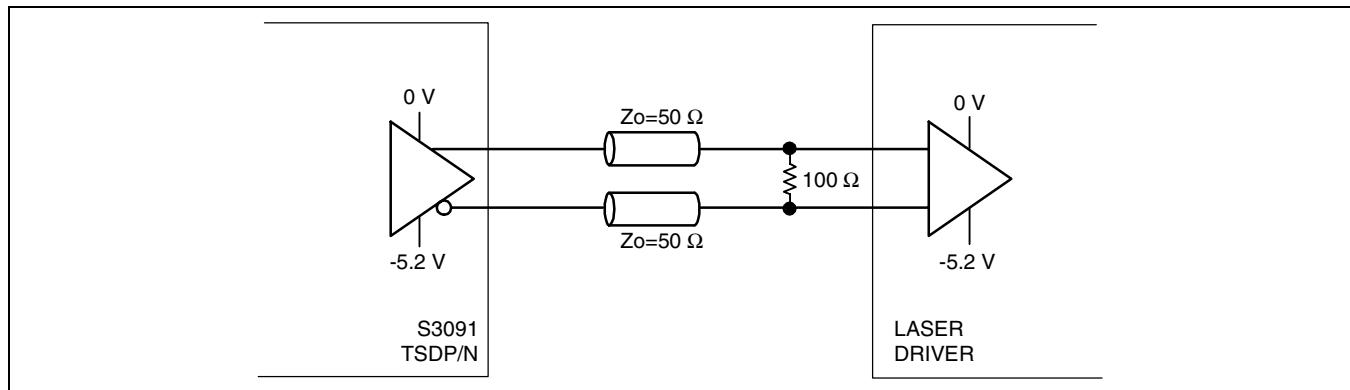


Figure 12. S3091 LVDS Driver to LVDS Input, Reference Only

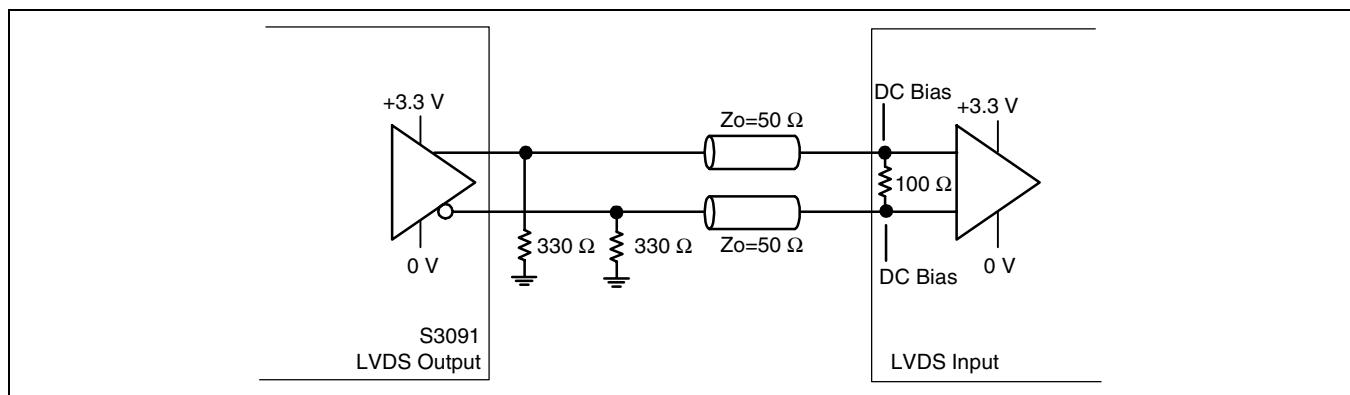


Figure 13. LVDS Driver to S3091 LVDS Input Direct Coupled Termination, Reference Only

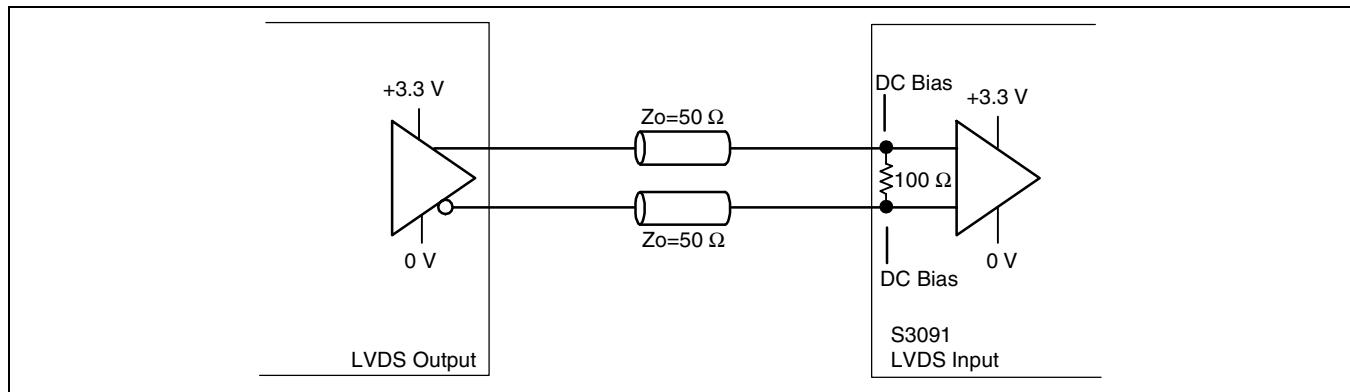


Figure 14. LVDS Driver to S3091 LVDS Input AC Coupled Termination, Reference Only

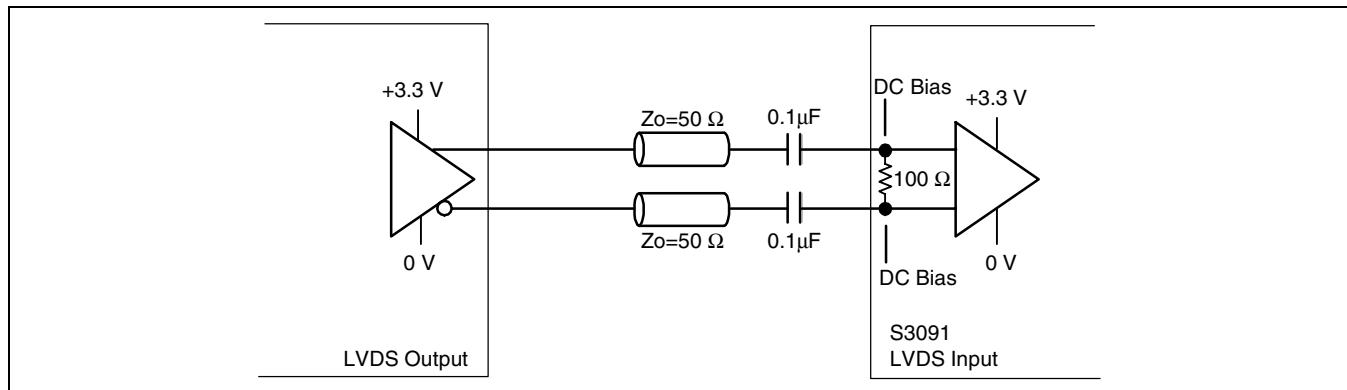


Figure 15. External Loop Filter

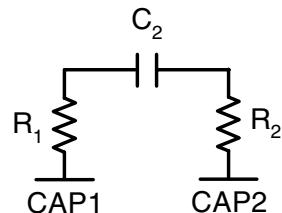
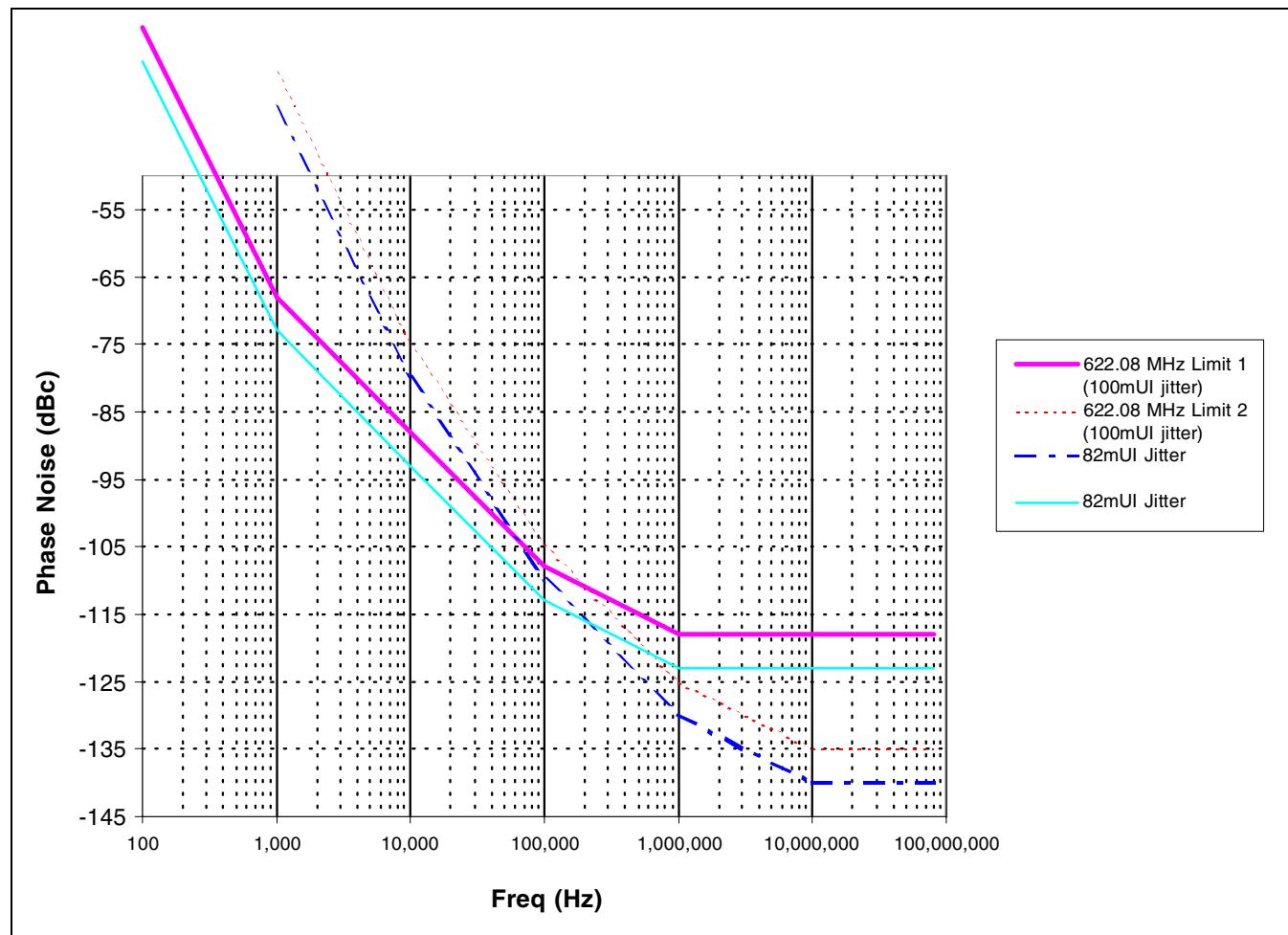
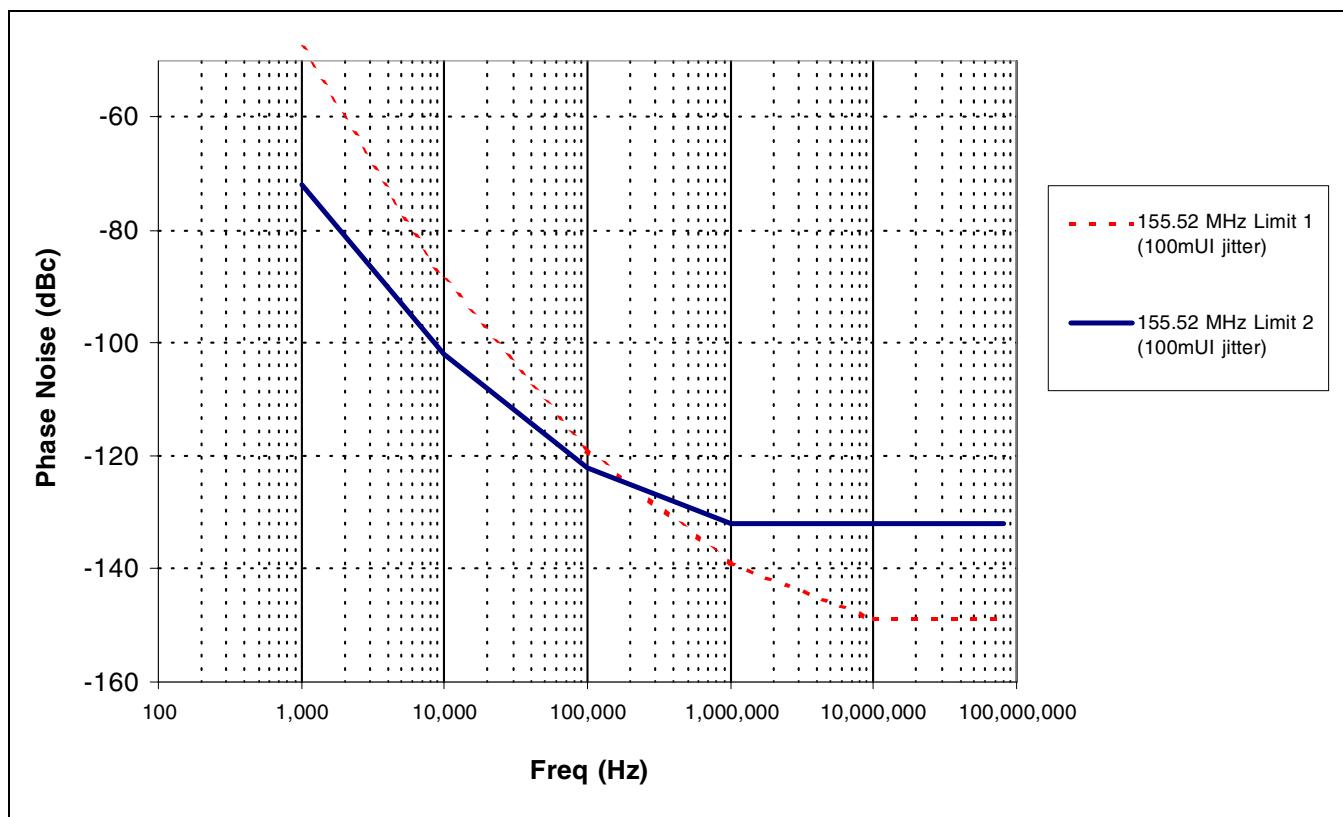


Figure 16. S3091 622.08 MHz REFCLK Phase Noise Limit



Note: Using an oscillator with one of the phase noise spectra shown above, will yield the respective jitter generation numbers associated with each phase noise plot.

Figure 17. S3091 155.52 MHz REFCLK Phase Noise Limit



Note: Using an oscillator with either phase noise spectrum shown above, will yield similar jitter generation as the integrated phase noise under each mask is similar.

**Ordering Information**

Prefix	Device	Package	Revision
S - Integrated Circuit	3091	CB - 148 CBGA	20

Prefix      Device      Package      Revision  
**X**      **XXXX**      **XX**      **XX**



*Applied Micro Circuits Corporation  
6290 Sequence Dr., San Diego, CA 92121*

*Phone: (858) 450-9333 — (800) 755-2622 — Fax: (858) 450-9885*

*<http://www.amcc.com>*

AMCC reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

AMCC does not assume any liability arising out of the application or use of any product or circuit described herein, neither does it convey any license under its patent rights nor the rights of others.

AMCC reserves the right to ship devices of higher grade in place of those of lower grade.

AMCC SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

AMCC is a registered trademark of Applied Micro Circuits Corporation. Copyright © 2002 Applied Micro Circuits Corporation.

D526/R971